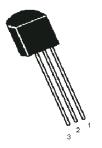
General Purpose Transistor







Pin Configuration:

- 1. Emitter
- 2. Base
- 3. Collector

Features:

- · NPN silicon planar epitaxial transistors
- General purpose transistors, best suited for use in driver stages of audio amplifiers, of tape recorders. Low noise input stages, Hi-Fi amplifiers, signal processing circuits of television receivers

Absolute Maximum Ratings

Parameters	Symbol	Value	Unit	
Collector Emitter Voltage	V _{CEO}	20		
Collector Base Voltage	V _{CBO}	30	V	
Emitter Base Voltage	V _{EBO}	5		
Collector Current Continuous	I _C	100	mA	
Power Dissipation at T _a = 25°C Derate above 25°C	D	625 5	mW mW/°C	
Power Dissipation at T _C = 25°C Derate above 25°C	P _D	1.5 12	W mW/°C	
Operating and Storage Junction Temperature Range	T _j , T _{stg}	-55 to +150	°C	

Thermal Resistance

Junction to Ambient	R _{th (j-a)}	200	°C/W
Junction to Case	R _{th (j-c)}	83.3	C/VV

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General Purpose Transistor



Electrical Characteristics ($T_a = 25$ °C unless otherwise specified)

Parameters	Symbol	Test Condition	Min.	Тур.	Max.	Units
Collector Emitter Voltage	V _{CEO}	$I_C = 1 \text{mA}, I_B = 0$	30	-	-	
Collector Base Voltage	V _{CBO}	$I_{\rm C} = 10 \mu A, I_{\rm E} = 0$	30	1	-	V
Emitter Base Voltage	V _{EBO}	$I_{E} = 10 \mu A, I_{C} = 0$	5	1	-	
Collector Cut off Current	I _{CBO}	$V_{CB} = 30V, I_{E} = 0$ $V_{CB} = 30V, I_{E} = 0,$ $T_{a} = +125^{\circ}C$	-	-	15 5	nΑ μΑ
Emitter Cut off Current	I _{EBO}	$V_{EB} = 4V, I_{C} = 0$	-	-	15	nA
DC Current Gain	h _{FE}	$V_{CE} = 5V, I_{C} = 10\mu A$ $V_{CE} = 5V, I_{C} = 2mA$	100 420	270 500	- 800	-
Collector Emitter Saturation Voltage	V _{CE (sat)}	$\begin{split} & \textbf{I}_{\text{C}} = \text{10mA}, \ \textbf{I}_{\text{B}} = \text{0.5mA} \\ & \textbf{I}_{\text{C}} = \text{10mA}, \ \textbf{I}_{\text{B}} = \text{see} \\ & \text{note1} \\ & \textbf{I}_{\text{C}} = \text{100mA}, \ \textbf{I}_{\text{B}} = \text{5mA*} \end{split}$	1	0.075 0.3 0.25	0.25 0.6 0.6	
Base Emitter Saturation Voltage	V _{BE (sat)}	$I_{\rm C} = 10 {\rm mA}, I_{\rm B} = 5 {\rm mA}^*$	-	1.1	-	V
Base Emitter on Voltage	V _{BE (on)}	$I_{C} = 10 \mu A, V_{CE} = 5V$ $I_{C} = 100 \mu A, V_{CE} = 5V$ $I_{C} = 2mA, V_{CE} = 5V$	0.55	0.52 0.55 0.62	0.7	

Dynamic Characteristics

Transition Frequency	f _T	$I_{C} = 10$ mA, $V_{CE} = 5$ V, f = 100MHz	-	250	-	MHz
Collector Output Capacitance	C_cbo	I _E = 0, V _{CE} = 10V f = 1MHz	-	2.5	-	pF
Noise Figure	NF ₁ *	$V_{CE} = 5V$, $I_{C} = 200\mu A$ $R_{S} = 2K\Omega$, f = 30Hz - 15kHz	-	0.6	2.5 10	dB
	NF ₂	$V_{CE} = 5V, I_{C} = 200 \mu A$ $R_{S} = 100 K \Omega, f = 1 kHz$				
Small Signal Current Gain	h _{fe}	V _{CE} = 5V, I _C = 2mA f = 1kHZ	450	600	900	-

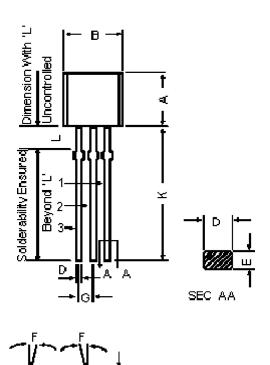
Note 1: I_B is value for which I_C = 11mA at V_{CE} = 1V *Pulse Condition: = Pulse Width ≤300 μ s, Duty Cycle ≤2%.

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General Purpose Transistor





Dimensions	Min.	Max.	
А	4.32	5.33	
В	4.45	5.2	
С	3.18	4.19	
D	0.41	0.55	
E	0.35	0.5	
F	5°		
G	1.14	1.4	
Н	1.14	1.53	
К	12.7	-	
L	1.982	2.082	

Dimensions: Millimetres

Pin Configuration:

- 1. Emitter
- 2. Base
- 3. Collector

Part Number Table

Description	Part Number	
Transistor, NPN, TO-92	BC549C	

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